

**TOSHIBA****TLRH247**

TENTATIVE

TOSHIBA LED LAMP InGaAlP RED LIGHT EMISSION

**TLRH247**

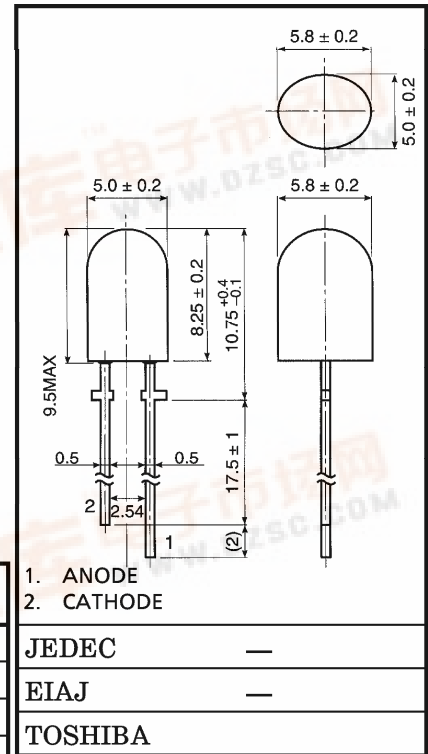
PANEL CIRCUIT INDICATOR

Unit in mm

- InGaAlP RED LED
- Elliptical Lens : Colorless Clear Lens
- Wide Radiation
- Low Drive Current, High Intensity Red Light Emission
- Plastic Molded Colorless Clear Lens Provides for High Contrast of ON-OFF Ratio.
- Fast Response Time, Capable of Pulse Operation.
- APPLICATIONS : Suitable for Outdoor Message Signboard, Full Color Panel, Backlight.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Forward Current	I <sub>F</sub>	50	mA
Reverse Voltage	V <sub>R</sub>	4	V
Power Dissipation	P <sub>D</sub>	125	mW
Operating Temperature Range	T <sub>opr</sub>	-30~85	°C
Storage Temperature Range	T <sub>stg</sub>	-40~120	°C



Weight : 0.3 g

ELECTRICAL AND OPTICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 20 mA	—	1.9	2.5	V
Reverse Current	I <sub>R</sub>	V <sub>R</sub> = 4 V	—	—	50	μA
Luminous Intensity	I <sub>V</sub>	I <sub>F</sub> = 20 mA (Note)	153	450	—	mcd
Peak Emission Wavelength	λ <sub>p</sub>	I <sub>F</sub> = 20 mA	—	644	—	nm
Spectral Line Half Width	Δλ	I <sub>F</sub> = 20 mA	—	18	—	nm
Dominant Wavelength	λ <sub>d</sub>	I <sub>F</sub> = 20 mA	—	630	—	nm

(Note) : Lamps are classified into the following ranks according to their luminous intensity.  
Measurement tolerance for each limit is ±15%.

P : 180~360 mcd, Q : 320~640 mcd, R : 560~1120 mcd.

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**PRECAUTION**

Please be careful of the followings

- Soldering temperature : 260°C max      Soldering time : 3 s max  
(Soldering portion of lead : bellow the lead stopper)
- If the lead is formed, the lead should be formed up to 5 mm from the body of the device without forming stress to the resin. Soldering should be performed after lead forming.
- This visible LED lamp also emits some IR light. If a photodetector is located near the LED lamp, please ensure that it will not be affected by this IR light.

